4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

JC817 Series

Features:

- Current transfer ratio (CTR: 50~600% at I_F =5mA, V_{CE} =5V)
- High isolation voltage between input and output (Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- Compact small outline package
- Pb free and RoHS compliant.





Description

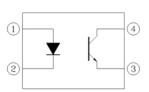
The JC817 series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Programmable controllers
- · System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

Schematic



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

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Absolute Maximum Ratings (T_a=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	50	mA
Input	Peak forward current (1us, pulse)	I _{FP}	1	А
	Reverse voltage	V_R	6	V
	Power dissipation		70	mW
	Derating factor (aboveT _a = 100°C)	P _D	2.9	mW/°C
	Power dissipation		150	mW
	Derating factor (above T _a = 100 °C)	P _C	5.8	mW/°C
Output	Collector current	Ic	50	mA
	Collector-Emitter voltage	V _{CEO}	35	V
	Emitter-Collector voltage	V _{ECO}	6	V
Total power dissipation		P _{TOT}	200	mW
Isolation voltage *1		V _{ISO}	5000	V rms
Operating temperature		T _{OPR}	-55 ~ +110	°C
Storage te	mperature	T _{STG}	-55 ~ +125	°C
Soldering t	temperature *2	T _{SOL}	260	°C

Notes

^{*1} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

^{*2} For 10 seconds.

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Electrical Characteristics (T_a=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Forward voltage	V _F	-	1.2	1.4	V	I _F = 20mA
Reverse current	I _R	-	-	10	μA	V _R = 4V
Input capacitance	C _{in}	-	30	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	$V_{CE} = 20V, I_F = 0mA$
Collector-Emitter breakdown voltage	BV _{CEO}	35	-	-	V	I _C = 0.1mA
Emitter-Collector breakdown voltage	BV _{ECO}	6	-	-	V	I _E = 0.1mA

Transfer Characteristics (T_a=25°C unless specified otherwise)

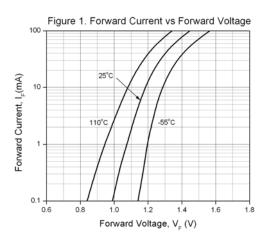
Parameter		Symbol	Min.	Тур.*	Max.	Unit	Condition
Current Transfer ratio	EL817	CTR	50	-	600	%	$I_F = 5 \text{mA}$, $V_{CE} = 5 \text{V}$
	EL817A		80	-	160		
	EL817B		130	-	260		
	EL817C		200	-	400		
	EL817D		300	-	600		
Collector-Emitter saturation voltage		V _{CE(sat)}	-	0.1	0.2	V	I _F = 20mA ,I _C = 1mA
Isolation resistance		R _{IO}	5×10 ¹⁰	ı	ı	Ω	V _{IO} = 500Vdc, 40~60% R.H.
Floating capacitance		C _{IO}	-	0.6	1.0	pF	V _{IO} = 0, f = 1MHz
Cut-off frequency		fc	1	80	-	kHz	$V_{CE} = 5V$, $I_C = 2mA$ $R_L = 100\Omega$, -3dB
Rise time		t _r	-	4	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$
Fall time		t _f	-	3	18	μs	$R_L = 100\Omega$

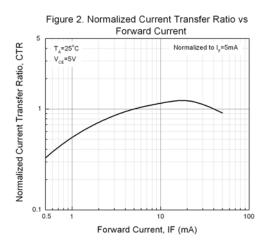
^{*} Typical values at T_a = 25°C

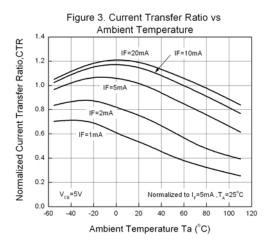
4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

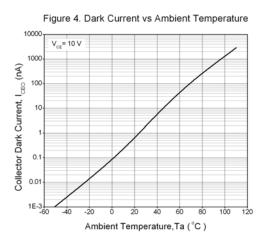
JC817 Series

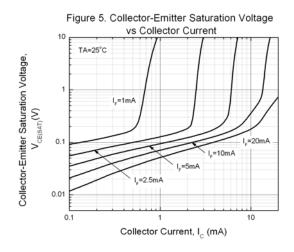
Typical Performance Curves

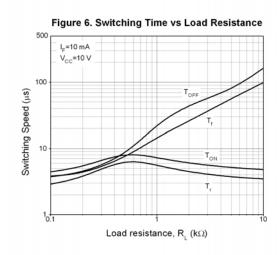












4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

JC817 Series

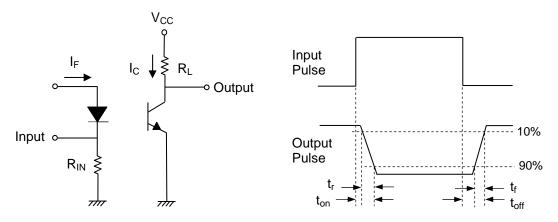


Figure 7. Switching Time Test Circuit & Waveforms

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Order Information

Part Number

Note

X = Lead form option (S, S1, M or none)

= CTR Rank (A, B, C, D or none)

Z = Tape and reel option (TA, TB, TU, TD or none).

= Lead frame option (F: Iron, None: copper)

V = VDE optin.

Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
M	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

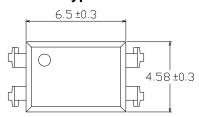
4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

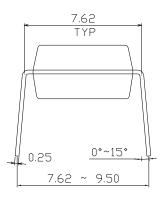
JC817 Series

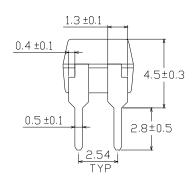
Package Drawing

(Dimensions in mm)

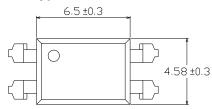
Standard DIP Type

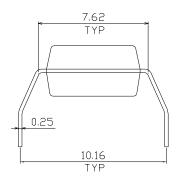


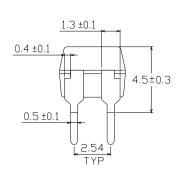




Option M Type



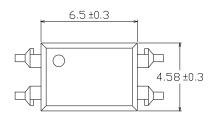


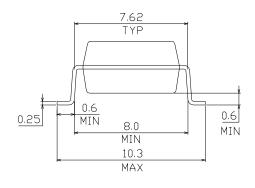


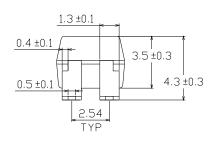
4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

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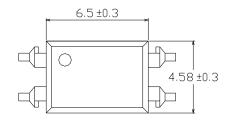
Option S Type

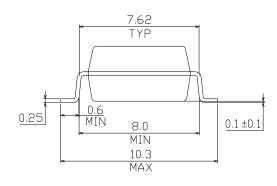


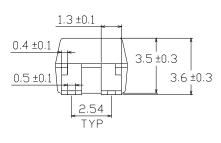




Option S1 Type



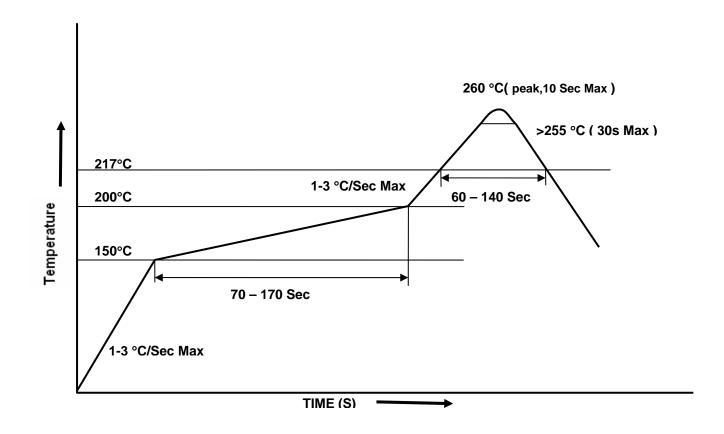




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Solder Reflow Temperature Profile



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